

GaAs MMIC VSAT Power Amplifier, 2W 5.9 - 6.4 GHz



Features

- High Linear Gain: 30 dB Typ.
- High Saturated Output Power: +33 dBm Typ.
- High Power Added Efficiency: 26% Typ.
- 50Ω Input/Output Broadband Matched
- High Performance Ceramic Bolt Down Package

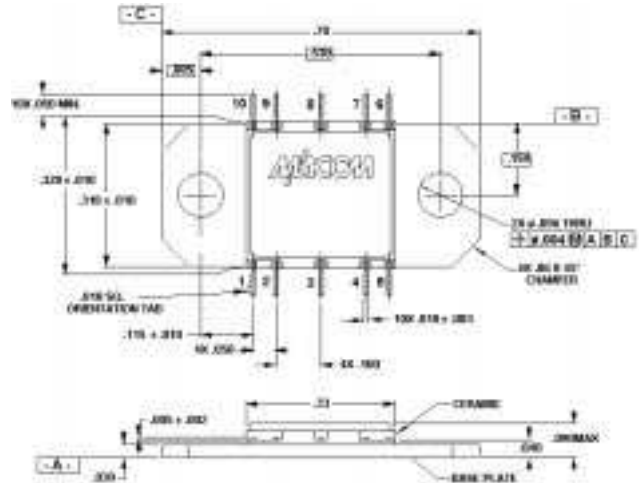
Description

M/A-COM's AM42-0040 is a three-stage MMIC power amplifier in a ceramic bolt down style hermetic package. The AM42-0040 employs an internally matched monolithic chip with internally decoupled Gate and Drain bias networks. The AM42-0040 is designed to be operated from a constant current Drain supply. By varying the Gate bias voltage, the saturated output power performance of this device can be tailored for various applications.

The AM42-0040 is designed for use as an output stage or driver amplifier for C-band VSAT transmitter systems. This amplifier employs a fully monolithic chip and requires a minimum of external components.

M/A-COM's AM42-0040 is fabricated using a mature 0.5 micron GaAs MESFET process. The process features full chip passivation for increased performance and reliability. These amplifiers are 100% RF tested to ensure compliance to performance specifications.

CR-15



Notes: (unless otherwise specified)

1. Dimensions are in inches.
2. Tolerance: .XXX = ± 0.005
.XX = ± 0.010

Ordering Information

Part Number	Package
AM42-0040	Ceramic Bolt Down Package

Electrical Specifications: $T_A = +25^\circ\text{C}$, $V_{DD} = +9\text{V}$, V_{GG} adjusted for $I_{DD} = 1050\text{ mA}$, Frequency = 5.9 to 6.4 GHz

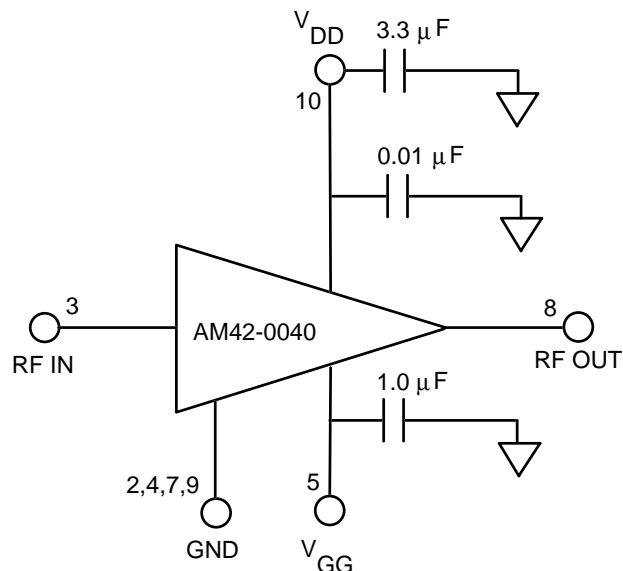
Parameter	Abbv.	Test Conditions	Units	Min.	Typ.	Max.
Linear Gain	G_L	$P_{IN} \leq -10\text{ dBm}$	dB	27	30	—
Input VSWR	$VSWR_{IN}$	$P_{IN} \leq -10\text{ dBm}$	—	—	2.3:1	2.7:1
Output VSWR	$VSWR_{OUT}$	$P_{IN} \leq -10\text{ dBm}$	—	—	3.0:1	—
Output Power	P_{SAT}	$P_{IN} = +10\text{ dBm}$, $I_{DD} = 1050\text{ mA}$ Typ.	dBm	31.7	33.0	34.3
Output Power vs. Frequency	P_{SAT}	$P_{IN} = +10\text{ dBm}$, $I_{DD} = 1050\text{ mA}$ Typ.	dB	—	1.0	1.5
Output Power vs. Temperature (with respect to $T_A = +25^\circ\text{C}$)	P_{SAT}	$P_{IN} = +10\text{ dBm}$, $I_{DD} = 1050\text{ mA}$ Typ. $T_A = -40^\circ\text{C}$ to $+70^\circ\text{C}$	dB	—	±0.4	—
Drain Bias Current	I_{DD}	$P_{IN} = +10\text{ dBm}$	mA	900	1050	1100
Gate Bias Voltage	V_{GG}	$P_{IN} = +10\text{ dBm}$, $I_{DD} = 1050\text{ mA}$ Typ.	V	-2.4	-1.2	-0.4
Gate Bias Current	I_{GG}	$P_{IN} = +10\text{ dBm}$, $I_{DD} = 1050\text{ mA}$ Typ.	mA	—	5	20
Thermal Resistance	θ_{JC}	25°C Heat Sink	°C/W	—	5.6	—
Second Harmonic	f_2	$P_{IN} = +10\text{ dBm}$, $I_{DD} = 1050\text{ mA}$ Typ.	dBc	—	-35	—
Third Harmonic	f_3	$P_{IN} = +10\text{ dBm}$, $I_{DD} = 1050\text{ mA}$ Typ.	dBc	—	-45	—

Absolute Maximum Ratings^{1,2,3,4}

Parameter	Absolute Maximum
Input Power	+23 dBm
V_{DD}	+12 Volts
V_{GG}	-3 Volts
$V_{DD} - V_{GG}$	12 Volts
I_{DD}	1700 mA
Channel Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

- Exceeding any one or a combination of these limits may cause permanent damage.
- Case Temperature (T_C) = +25°C.
- Nominal bias is obtained by first connecting -2.4 volts to pin 5 (V_{GG}), followed by connecting +9 volts to pin 10 (V_{DD}). Note sequence. Adjust V_{GG} for a drain current of 1050 mA typical.
- RF ground and thermal interface is the flange (case bottom). Adequate heat sinking is required.
- No dc supply voltage will appear at the RF ports.
- The dc resistance at the input and output ports is a short circuit. No voltage is allowed on these ports.
- For optimum IP_3 performance, the V_{DD} bypass capacitors should be placed within 0.5 inches of the V_{DD} leads.

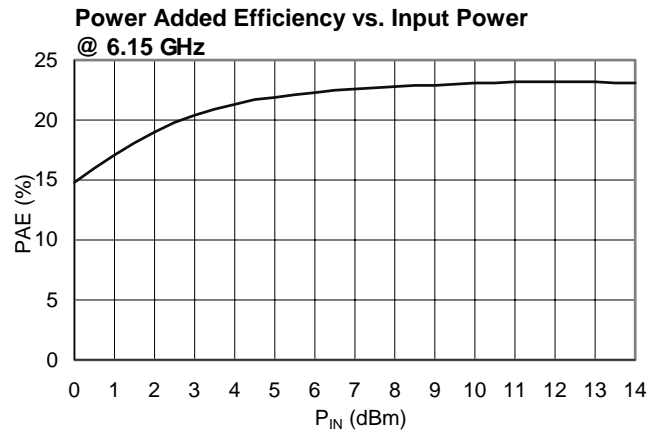
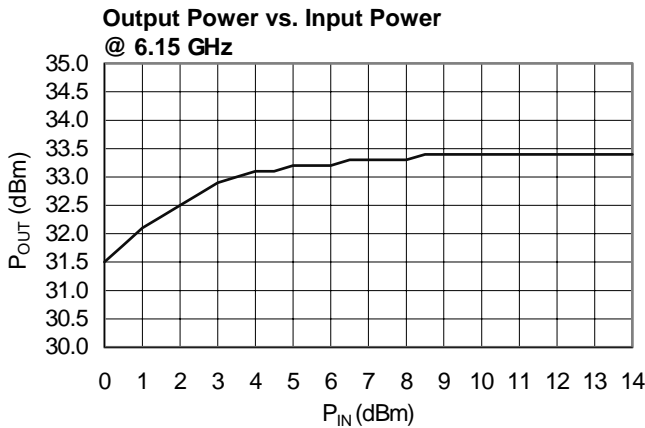
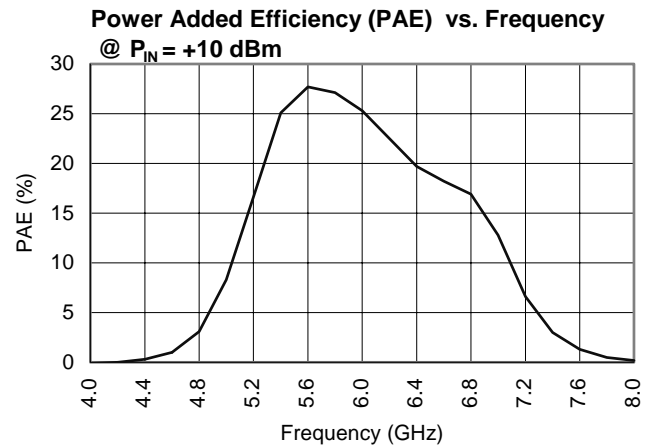
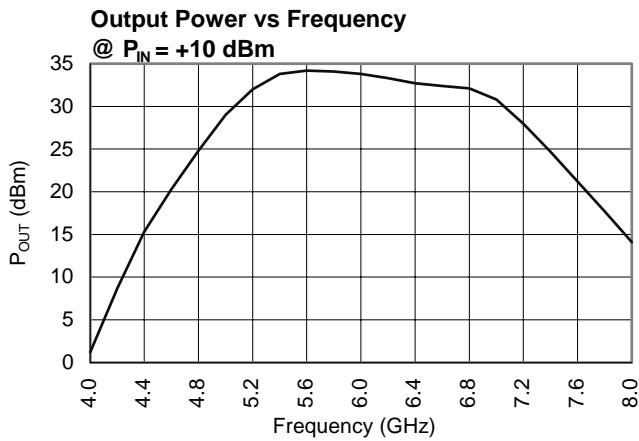
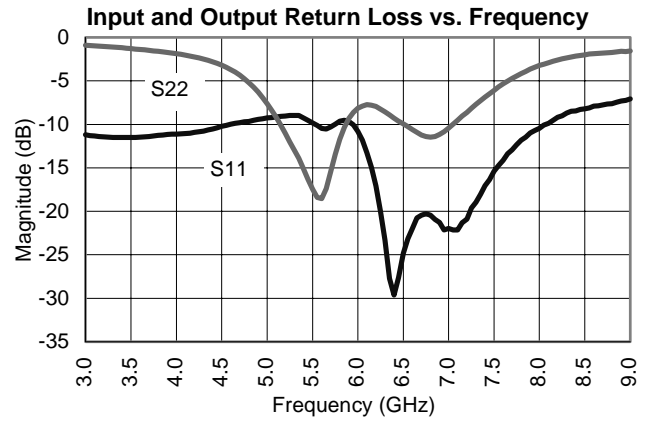
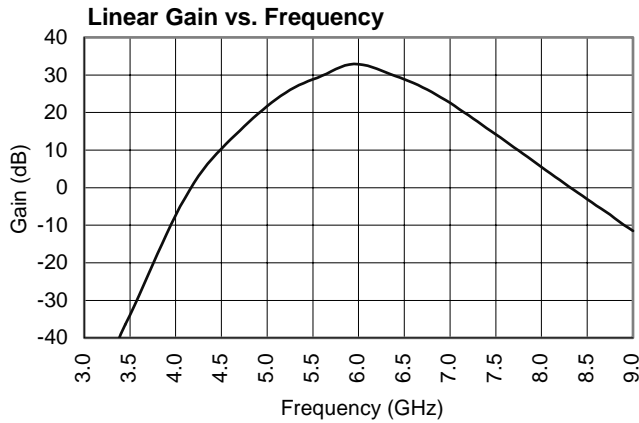
Typical Bias Configuration^{4,5,6,7}



Pin Configuration

Pin No.	Pin Name	Description
1	N/C	No Connection
2	GND	DC and RF Ground
3	RF In	RF Input
4	GND	DC and RF Ground
5	V_{GG}	Gate Supply
6	N/C	No Connection
7	GND	DC and RF Ground
8	RF Out	RF Output
9	GND	DC and RF Ground
10	V_{DD}	Drain Supply

Typical Performance @ +25°C



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